

**ON Semiconductor**<sup>®</sup>

# 74AC14, 74ACT14 Hex Inverter with Schmitt Trigger Input

# Features

- I<sub>CC</sub> reduced by 50%
- Outputs source/sink 24mA
- 74ACT14 has TTL-compatible inputs

# **General Description**

The 74AC14 and 74ACT14 contain six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

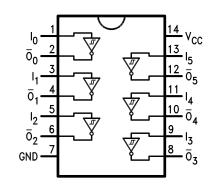
The 74AC14 and 74ACT14 have hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

# **Ordering Information**

Order Number	Package Number	Package Description
74AC14SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74AC14SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT14SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74ACT14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

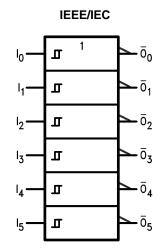
# **Connection Diagram**



# **Pin Description**

Pin Names	Description
I <sub>n</sub>	Inputs
Ōn	Outputs

Logic Symbol



# **Function Table**

Input	Output
Α	ō
L	Н
Н	L

# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	-0.5V to +7.0V
I <sub>IK</sub>	DC Input Diode Current	
	V <sub>I</sub> = -0.5V	–20mA
	$V_{I} = V_{CC} + 1.5$	+20mA
VI	DC Input Voltage	–0.5V to V <sub>CC</sub> + 1.5V
I <sub>OK</sub>	DC Output Diode Current	
	$V_{O} = -0.5V$	–20mA
	$V_{O} = V_{CC} + 0.5V$	+20mA
Vo	DC Output Voltage	–0.5V to V <sub>CC</sub> + 0.5V
Ι <sub>Ο</sub>	DC Output Source or Sink Current	±50mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or Ground Current per Output Pin	±50mA
T <sub>STG</sub>	Storage Temperature	–65°C to +150°C
Τ <sub>J</sub>	Junction Temperature	140°C

# **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	
	AC	2.0V to 6.0V
	ACT	4.5V to 5.5V
VI	Input Voltage	0V to V <sub>CC</sub>
Vo	Output Voltage	0V to V <sub>CC</sub>
Τ <sub>Α</sub>	Operating Temperature	–40°C to +85°C

	Parameter	v <sub>cc</sub>	Conditions	<b>T</b> <sub>A</sub> = -	+25°C	T <sub>A</sub> = -40°C to +85°C	Units
Symbol		(V)		Тур	Guara	nteed Limits	
V <sub>OH</sub>	Minimum HIGH Level	3.0	Ι <sub>ΟUT</sub> = –50μΑ	2.99	2.9	2.9	V
	Output Voltage	4.5		4.49	4.4	4.4	
		5.5		5.49	5.4	5.4	
		3.0	I <sub>OH</sub> = 12mA		2.56	2.46	
		4.5	$I_{OH} = 24mA$		3.86	3.76	
		5.5	$I_{OH} = 24 m A^{(1)}$		4.86	4.76	
V <sub>OL</sub>	Maximum LOW Level	3.0	I <sub>OUT</sub> = 50μA	0.002	0.1	0.1	V
	Output Voltage	4.5		0.001	0.1	0.1	
		5.5		0.001	0.1	0.1	
		3.0	$I_{OL} = 12mA$		0.36	0.44	
		4.5	$I_{OL} = 24 mA$		0.36	0.44	
		5.5	$I_{OL} = 24 m A^{(1)}$		0.36	0.44	
I <sub>IN</sub> <sup>(3)</sup>	Maximum Input Leakage Current	5.5	$V_I = V_{CC}, GND$		±0.1	±1.0	μA
V <sub>t+</sub>	Maximum Positive Threshold	3.0	T <sub>A</sub> = Worst Case		2.2	2.2	V
		4.5			3.2	3.2	
		5.5			3.9	3.9	
V <sub>t</sub> -	Minimum Negative Threshold	3.0	T <sub>A</sub> = Worst Case		0.5	0.5	V
		4.5			0.9	0.9	
		5.5			1.1	1.1	
V <sub>H(MAX)</sub>	Maximum Hysteresis	3.0	T <sub>A</sub> = Worst Case		1.2	1.2	V
		4.5			1.4	1.4	
		5.5			1.6	1.6	
V <sub>H(MIN)</sub>	Minimum Hysteresis	3.0	T <sub>A</sub> = Worst Case		0.3	0.3	V
-		4.5	1		0.4	0.4	1
		5.5	]		0.5	0.5	
I <sub>OLD</sub>	Minimum Dynamic	5.5	$V_{OLD} = 1.65V$ Max.			75	mA
I <sub>OHD</sub>	Output Current <sup>(2)</sup>	5.5	V <sub>OHD</sub> = 3.85V Min.			-75	mA
$I_{CC}^{(3)}$	Maximum Quiescent Supply Current	5.5	$V_{IN} = V_{CC} \text{ or } GND$		2.0	20.0	μA

74AC14, 74ACT14 — Hex Inverter with Schmitt Trigger Input

## Notes:

1. All outputs loaded; thresholds on input associated with output under test.

2. Maximum test duration 2.0ms, one output loaded at a time.

3.  $I_{\rm IN}$  and  $I_{\rm CC}$  @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V  $V_{\rm CC}.$ 

		V <sub>CC</sub>		T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to +85°C	
Symbol	Parameter	(V)	Conditions	Тур.	p. Guaranteed Limits		Units
V <sub>IH</sub>	Minimum HIGH Level	4.5	$V_{OUT} = 0.1V$ or	1.5	2.0	2.0	V
	Input Voltage	5.5	V <sub>CC</sub> – 0.1V	1.5	2.0	2.0	
VIL	Maximum LOW Level	4.5	$V_{OUT} = 0.1V$ or	1.5	0.8	0.8	V
	Input Voltage	5.5	V <sub>CC</sub> – 0.1V	1.5	0.8	0.8	-
V <sub>OH</sub>	Minimum HIGH Level	4.5	Ι <sub>ΟUT</sub> = –50μΑ	4.49	4.34	4.4	V
	Output Voltage	5.5		5.49	5.4	5.4	
		4.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -24 \text{mA}$		3.86	3.76	
		5.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -24 \text{mA}^{(4)}$		4.86	4.76	
UL	Maximum LOW Level	4.5	Ι <sub>ΟUT</sub> = 50μΑ	0.001	0.1	0.1	V
	Output Voltage	5.5	-	0.001	0.1	0.1	
		4.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 24 \text{mA}$		0.36	0.44	
		5.5	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 24 \text{mA}^{(4)}$		0.36	0.44	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	$V_I = V_{CC}, GND$		±0.1	±1.0	μA
V <sub>H(MAX)</sub>	Maximum Hysteresis	4.5	$T_A = Worst Case$		1.4	1.4	V
		5.5	-		1.6	1.6	
V <sub>H(MIN)</sub>	Minimum Hysteresis	4.5	T <sub>A</sub> = Worst Case		0.4	0.4	V
		5.5	-		0.5	0.5	
V <sub>t+</sub>	Maximum Positive	4.5	T <sub>A</sub> = Worst Case		2.0	2.0	V
	Threshold	5.5	-		2.0	2.0	
V <sub>t-</sub>	Minimum Negative	4.5	$T_A = Worst Case$		0.8	0.8	V
	Threshold	5.5	1		0.8	0.8	1
I <sub>CCT</sub>	Maximum I <sub>CC</sub> /Input	5.5	$V_I = V_{CC} - 2.1V$	0.6		1.5	mA
I <sub>OLD</sub>	Minimum Dynamic	5.5	$V_{OLD} = 1.65 V$ Max.			75	mA
I <sub>OHD</sub>	Output Current <sup>(5)</sup>	5.5	$V_{OHD} = 3.85V$ Min.			-75	mA
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$ or GND		2.0	20.0	μA

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## Notes:

4. All outputs loaded; thresholds on input associated with output under test.

5. Maximum test duration 2.0ms, one output loaded at a time.

# AC Electrical Characteristics for AC

			T <sub>A</sub> = +25°C, C <sub>L</sub> = 50pF		$ \begin{array}{c} T_A = -40^\circ C \text{ to } +85^\circ C, \\ C_L = 50 p F \end{array} $			
Symbol	Parameter	V <sub>CC</sub> (V) <sup>(6)</sup>	Min.	Тур.	Max.	Min.	Max.	Units
t <sub>PLH</sub>	Propagation Delay	3.3	1.5	9.5	13.5	1.5	15.0	ns
		5.0	1.5	7.0	10.0	1.5	11.0	
t <sub>PHL</sub>	Propagation Delay	3.3	1.5	7.5	11.5	1.5	13.0	ns
		5.0	1.5	6.0	8.5	1.5	9.5	

## Note:

6. Voltage range 3.3 is 3.3V  $\pm$  0.3V. Voltage range 5.0 is 5.0V  $\pm$  0.5V.

# **AC Electrical Characteristics for ACT**

			T <sub>A</sub> = +25°C, C <sub>L</sub> = 50pF		$\label{eq:TA} \begin{array}{l} T_A = -40^\circ C \text{ to } +85^\circ C, \\ C_L = 50 p F \end{array}$			
Symbol	Parameter	V <sub>CC</sub> (V) <sup>(7)</sup>	Min.	Тур.	Max.	Min.	Max.	Units
t <sub>PLH</sub>	Propagation Delay	5.0	3.0	8.0	10.0	3.0	11.0	ns
t <sub>PHL</sub>	Propagation Delay	5.0	3.0	8.0	10.0	3.0	11.0	ns

## Note:

7. Voltage Range 5.0 is  $5.0V \pm 0.5V$ .

# Capacitance

Symbol	Parameter	Conditions	Тур	Units
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = OPEN	4.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC} = 5.0V$		
	AC		25.0	pF
	ACT		80	

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